



# CMD219C4

## 4-8 GHz GaN Low Noise Amplifier

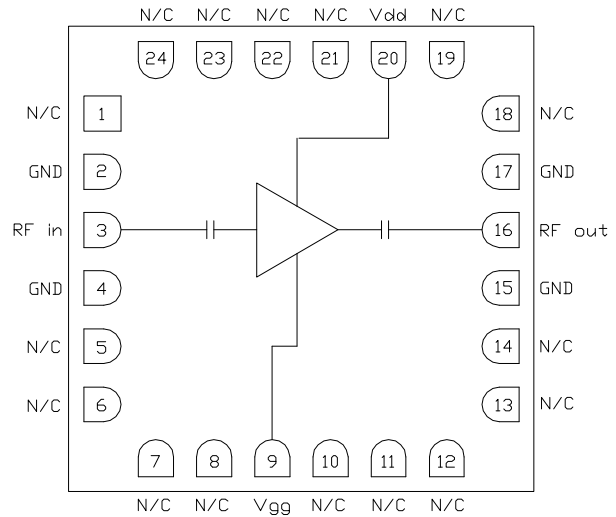
### Features

- ▶ High gain
- ▶ Low noise figure
- ▶ High linearity
- ▶ High RF power survivability
- ▶ Pb-free RoHs compliant 4x4 QFN package

### Description

The CMD219C4 is a broadband MMIC GaN low noise amplifier housed in a leadless 4x4 mm QFN package. The CMD219C4 is ideally suited for microwave radios and C-band applications where small size and high input power survivability are needed. The broadband device delivers greater than 22.5 dB of gain with a corresponding output 1 dB compression point of +17 dBm and a noise figure of 1 dB. The CMD219C4 features a RF input power survivability of greater than 5 Watts.

### Functional Block Diagram



### Electrical Performance - $V_{dd} = 10\text{ V}$ , $V_{gg} = -2.3\text{ V}$ , $T_A = 25\text{ }^\circ\text{C}$ , $F = 6\text{ GHz}$

Parameter	Min	Typ	Max	Units
Frequency Range	4 - 8			GHz
Gain		22.5		dB
Noise Figure		1		dB
Output P1dB		17		dBm
Output Psat		25.5		dBm
Output IP3		28		dBm
Input Return Loss		13		dB
Output Return Loss		10		dB
Supply Current		75		mA

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### Specifications

#### Absolute Maximum Ratings

Parameter	Rating
Drain Voltage, V <sub>dd</sub>	35 V
RF Input Power	5 W Pulsed
Channel Temperature, T <sub>ch</sub>	150 °C
Power Dissipation, P <sub>diss</sub>	3.5 W
Thermal Resistance	18.7 °C/W
Operating Temperature	-55 to 85 °C
Storage Temperature	-55 to 150 °C

Operation of this device outside the maximum ratings may cause permanent damage.

#### Recommended Operating Conditions

Parameter	Min	Typ	Max	Units
V <sub>dd</sub>	5	10	28	V
I <sub>dd</sub>		75		mA
V <sub>gg</sub>	-10		-1	V

Electrical performance is measured at specific test conditions. Electrical specifications are not guaranteed over all recommended operating conditions.

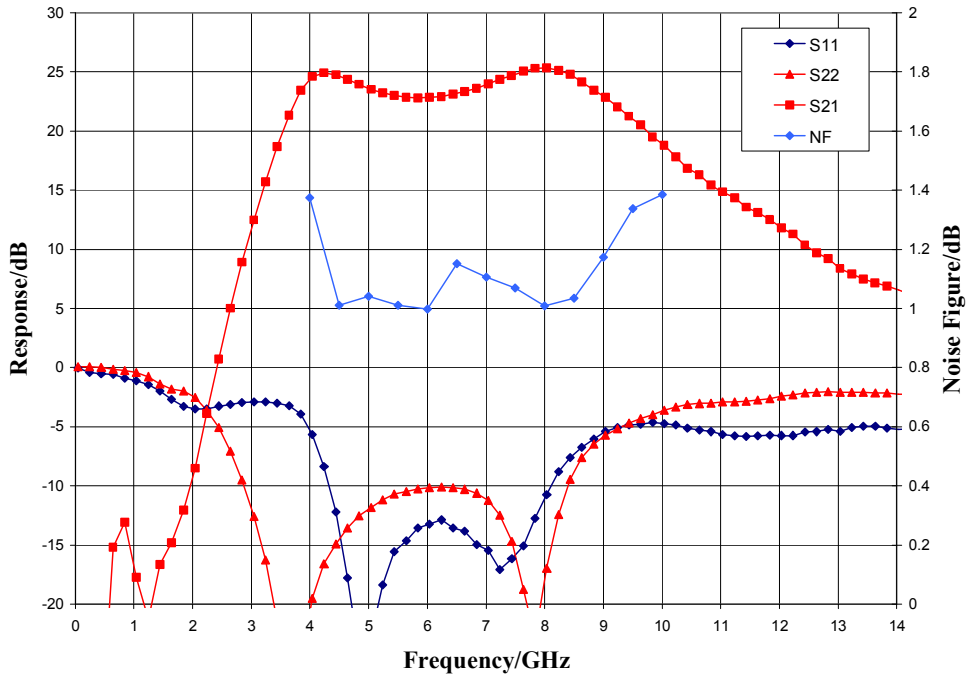
#### Electrical Specifications - V<sub>dd</sub> = 10 V, V<sub>gg</sub> = -2.3 V, T<sub>A</sub> = 25 °C

Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range	5 - 7			4 - 8			GHz
Gain	20	23	27	20	23	28	dB
Noise Figure		1.05	1.4		1.1	1.7	dB
Input Return Loss		13			10		dB
Output Return Loss		10			12		dB
Output P <sub>1dB</sub>		17			18		dBm
Output IP <sub>3</sub>		28			28		dBm
Supply Current	52	75	98	52	75	98	mA
Gain Temperature Coefficient		0.03			0.03		dB/°C
Noise Figure Temperature Coefficient		0.01			0.01		dB/°C

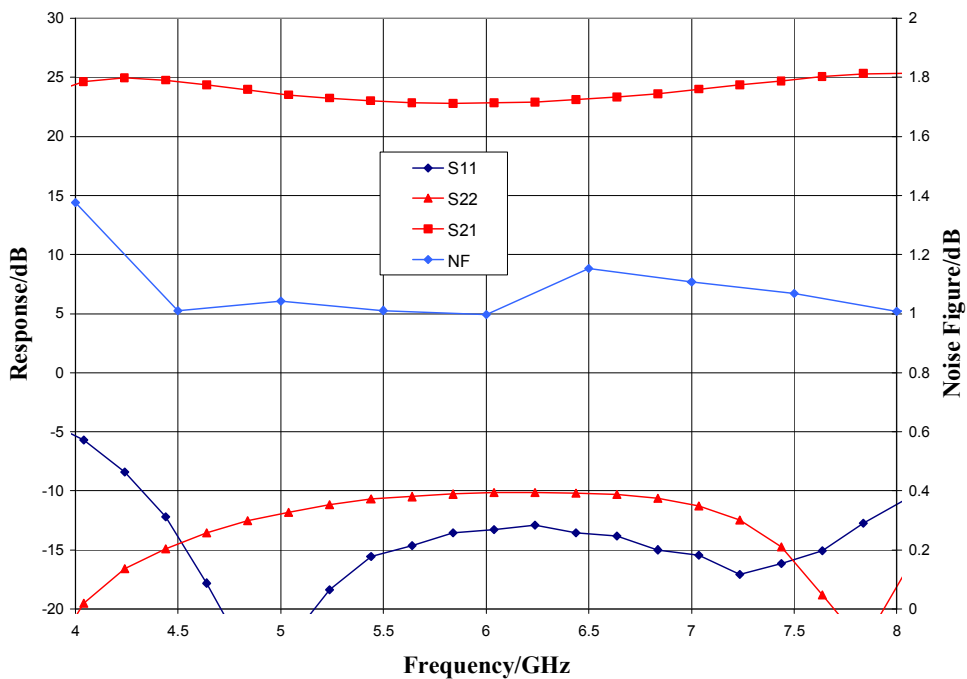
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### Typical Performance

**Broadband Performance,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -2.3\text{ V}$ ,  $I_{dd} = 75\text{ mA}$ ,  $T_A = 25\text{ }^\circ\text{C}$**



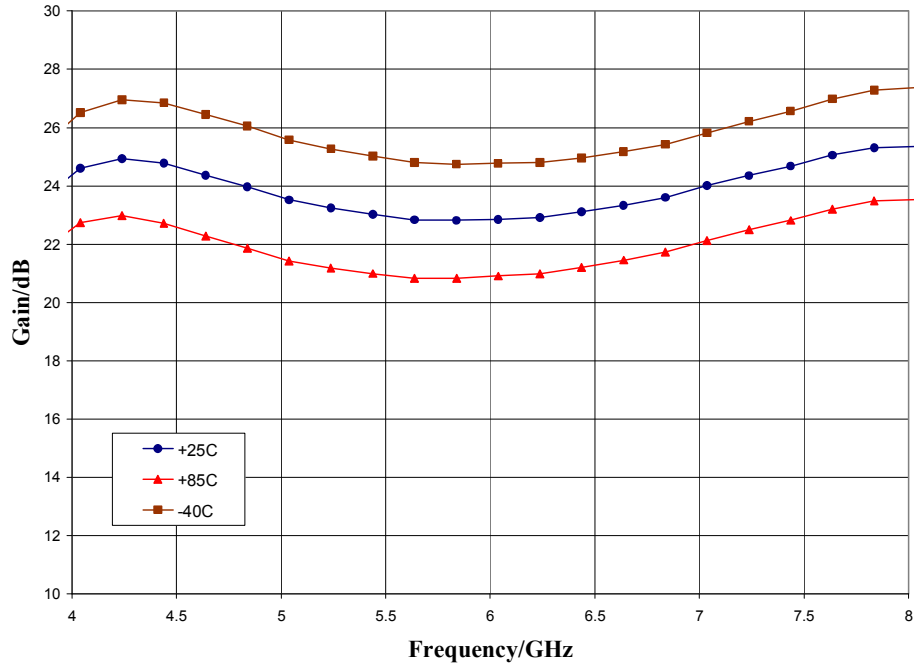
**Narrow-band Performance,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -2.3\text{ V}$ ,  $I_{dd} = 75\text{ mA}$ ,  $T_A = 25\text{ }^\circ\text{C}$**



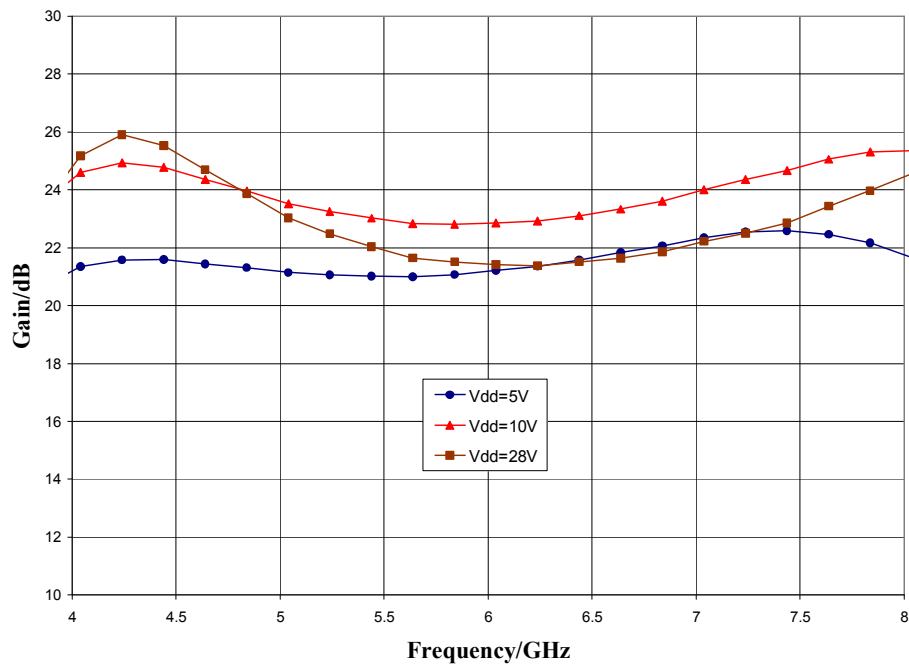
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### Typical Performance

Gain vs. Temperature,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -2.3\text{ V}$



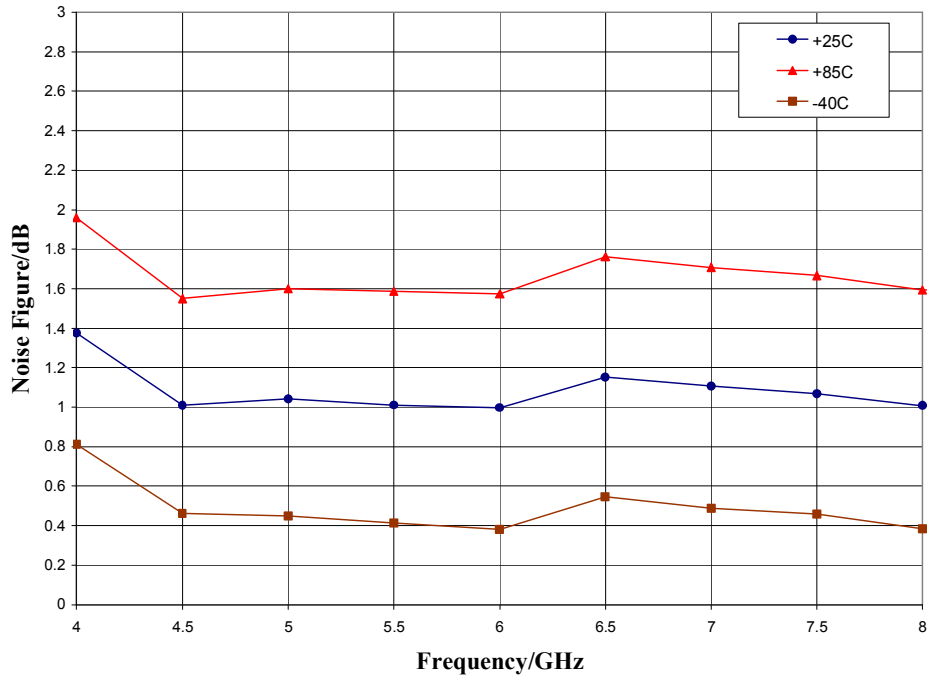
Gain vs.  $V_{dd}$ ,  $V_{gg} = -2.3\text{ V}$ ,  $T_A = 25\text{ }^\circ\text{C}$



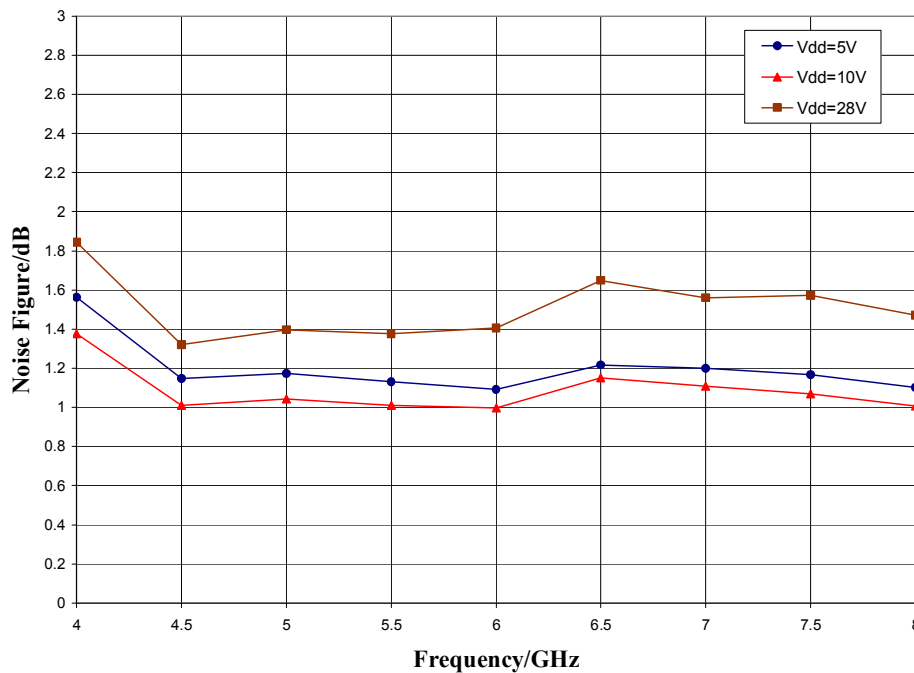
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### Typical Performance

**Noise Figure vs. Temperature,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -2.3\text{ V}$**



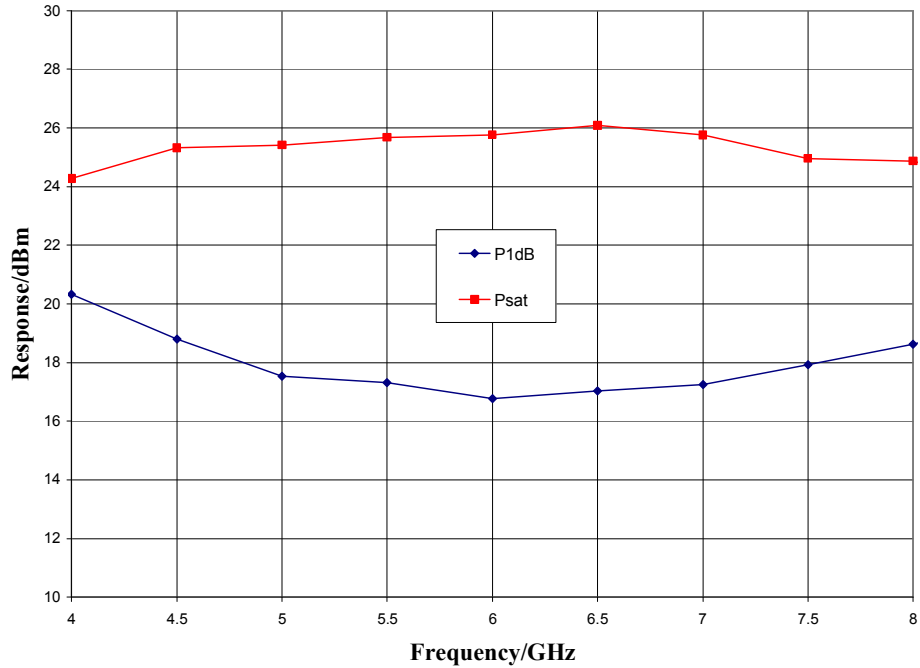
**Noise Figure vs.  $V_{dd}$ ,  $V_{gg} = -2.3\text{ V}$ ,  $T_A = 25\text{ }^\circ\text{C}$**



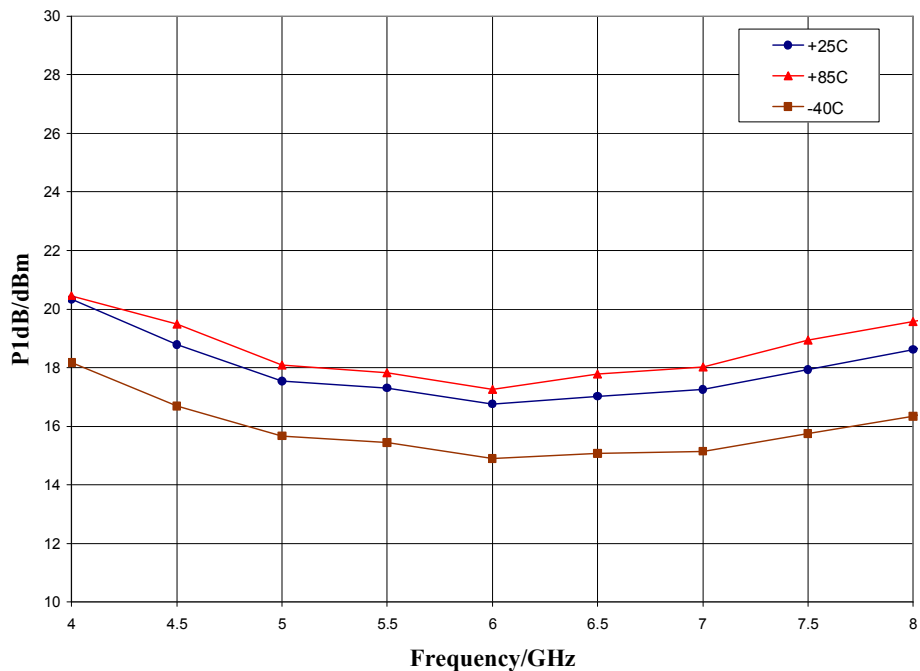
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### Typical Performance

**Output Power,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -2.3\text{ V}$ ,  $T_A = 25\text{ }^\circ\text{C}$**



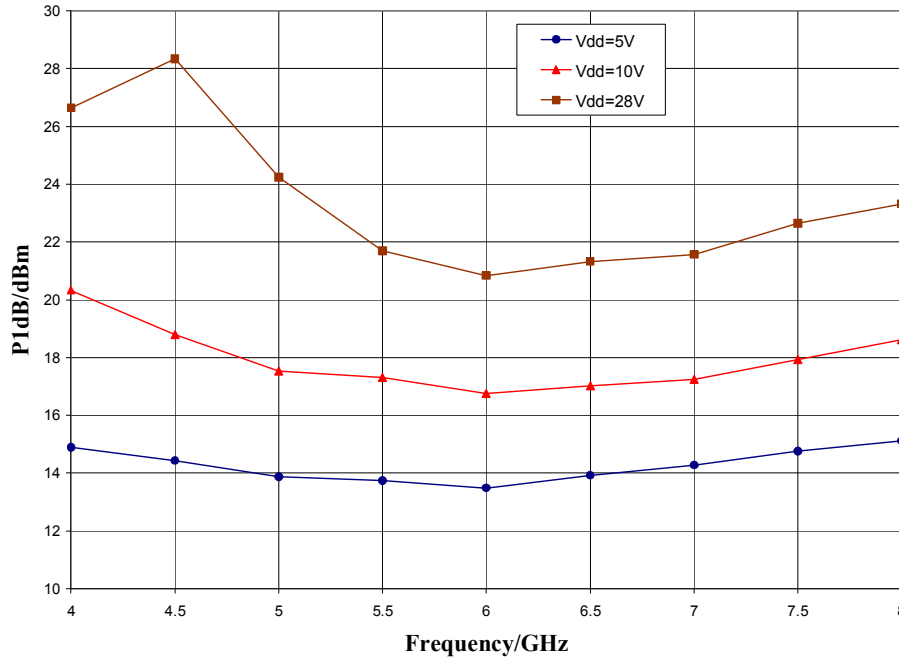
**P1dB vs. Temperature,  $V_{dd} = 10\text{ V}$ ,  $V_{gg} = -2.3\text{ V}$**



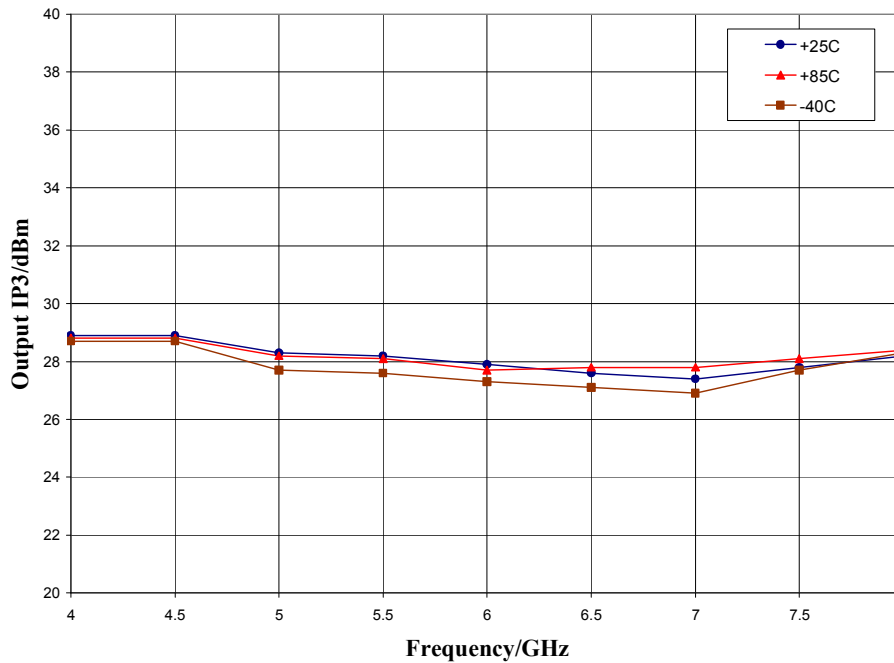
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### Typical Performance

**P1dB vs.  $V_{dd}$ ,  $V_{gg} = -2.3$  V,  $T_A = 25$  °C**



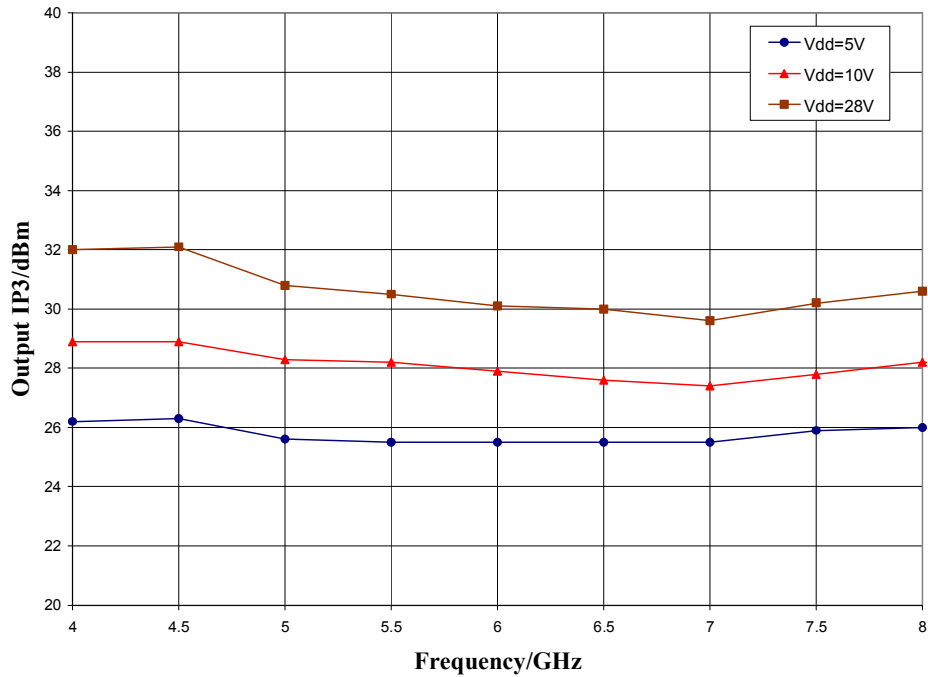
**Output IP3 vs. Temperature,  $V_{dd} = 10$  V,  $V_{gg} = -2.3$  V**



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### Typical Performance

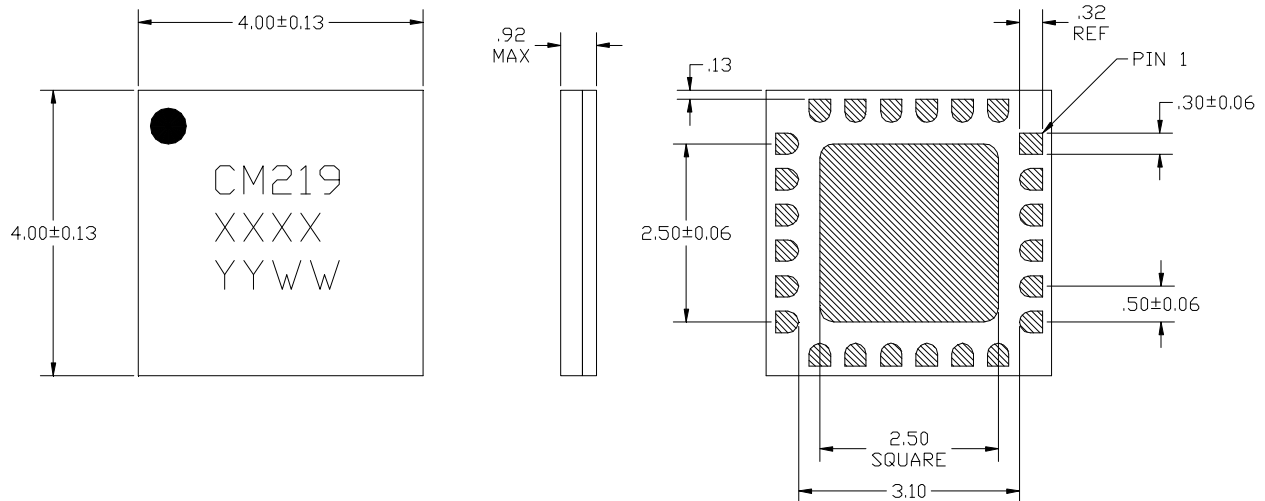
Output IP3 vs.  $V_{dd}$ ,  $V_{gg} = -2.3$  V,  $T_A = 25$  °C





### Mechanical Information

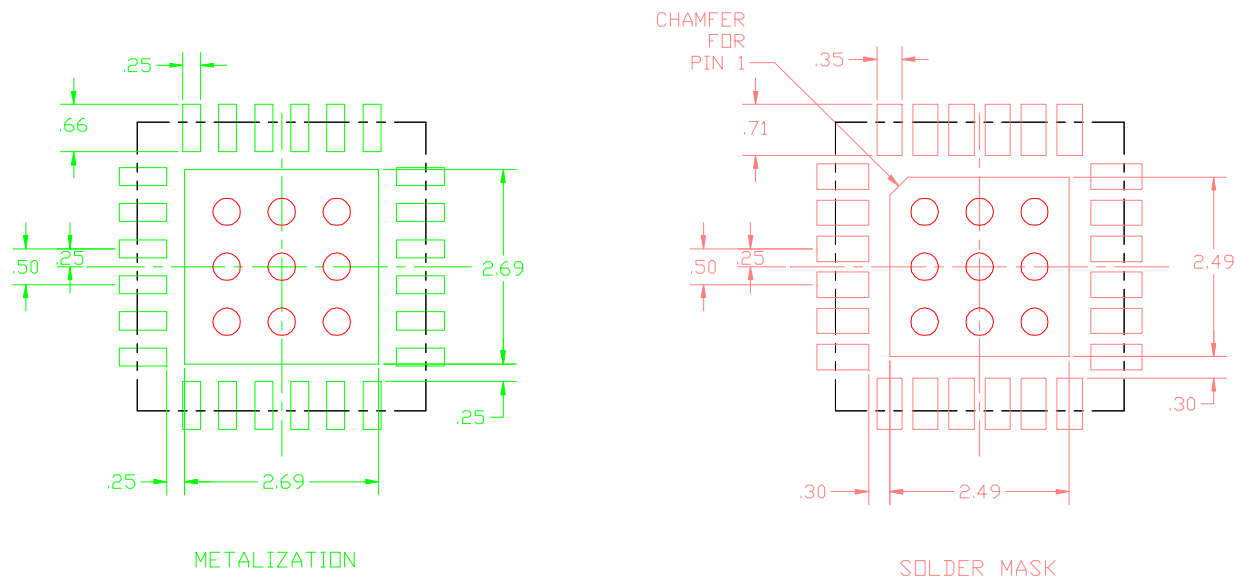
#### Package Information and Dimensions



**NOTES:**

1. DIMENSIONS ARE IN MILLIMETERS
2. MATERIAL: BLACK ALUMINA
3. LEAD FINISH: 30-80 MICROINCHES GOLD OVER 50 MICROINCHES NICKEL.
4. ALTERNATE PIN #1 IDENTIFIER IS SINGLE SQUARE PAD.

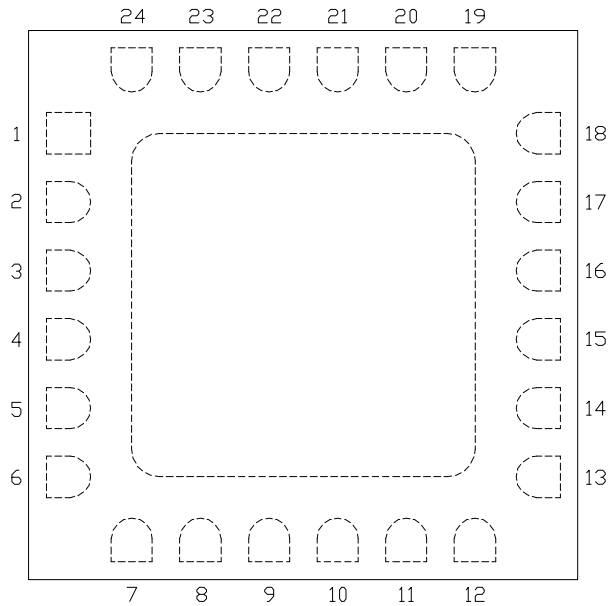
#### Recommended PCB Land Pattern




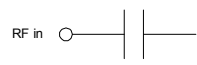
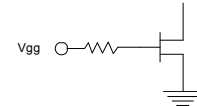

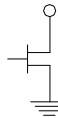
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### Pin Description

#### Pin Diagram



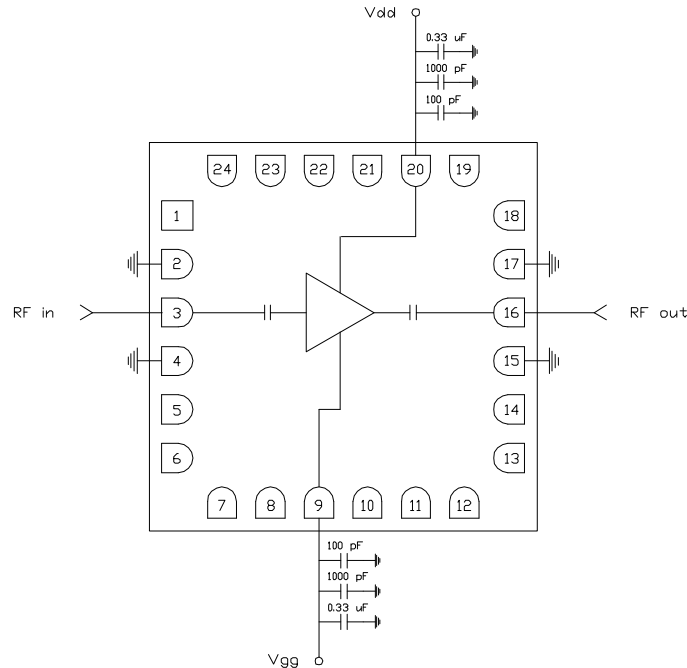
#### Functional Description

Pin	Function	Description	Schematic
1, 5-8, 10-14, 18, 19, 21-24	N/C	No connection required. These pins may be connected to RF/DC ground	
2, 4, 15, 17 and die paddle	Ground	Connect to RF/DC ground	
3	RF in	DC blocked and 50 ohm matched	
9	V <sub>gg</sub>	Power supply voltage Decoupling and bypass caps required	
16	RF out	DC blocked and 50 ohm matched	
20	V <sub>dd</sub>	Power supply voltage Decoupling and bypass caps required	

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### Applications Information

#### Application Circuit



#### Biasing and Operation

The CMD219C4 is biased with a positive drain supply and a negative gate supply. Performance is optimized when the drain voltage is set to +10 V but may be set between +5 V and +28 V.

Turn ON procedure:

1. Apply gate voltage  $V_{gg}$  and set to a voltage sufficient to pinch off drain current ( $\sim -4$  V)
2. Apply drain voltage  $V_{dd}$  and set to +10 V
3. Increase  $V_{gg}$  (less negative) to achieve a drain current of 75 mA

Turn OFF procedure:

1. Turn off drain voltage  $V_{dd}$
2. Turn off gate voltage  $V_{gg}$

RF power can be applied at any time

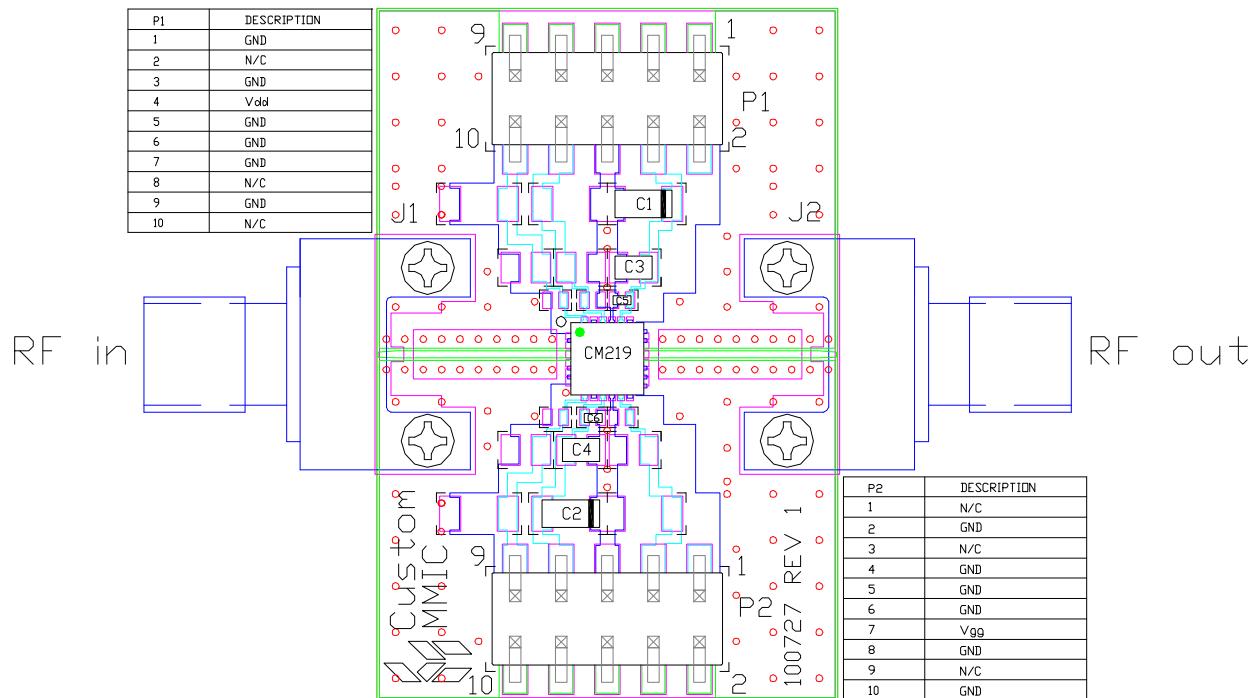
**GaAs MMIC devices are susceptible to damage from Electrostatic Discharge. Proper precautions should be observed during handling, assembly and test.**

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### Applications Information

#### Evaluation Board

The circuit board shown has been developed for optimized assembly at CMDS. A sufficient number of via holes should be used to connect the top and bottom ground planes. As surface mount processes vary, careful process development is recommended.



#### Bill of Material

Designator	Value	Description
J1, J2		SMA End Launch Connector
P1, P2		10 Pin Header
C1, C2	0.33 $\mu$ F	Capacitor, Tantalum
C3, C4	1000 pF	Capacitor, 0603
C5, C6	100 pF	Capacitor, 0402
U1		CMD219C4 Low Noise Amplifier
PCB		100727 Evaluation PCB

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